

## **FEATURES**

- \* 3.0 -INCH ( 76.2 -mm) MATRIX HEIGHT.
- \* LOW POWER REQUIREMENT.
- \* EXCELLENT CHARACTERS APPEARANCE.
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* WIDE VIEWING ANGLE.
- \* SOLID STATE RELIABILITY.
- \* CATEGORIZED FOR LUMINOUS INTENSITY.
- \* STACKABLE VERTICALLY AND HORIZONTALLY.

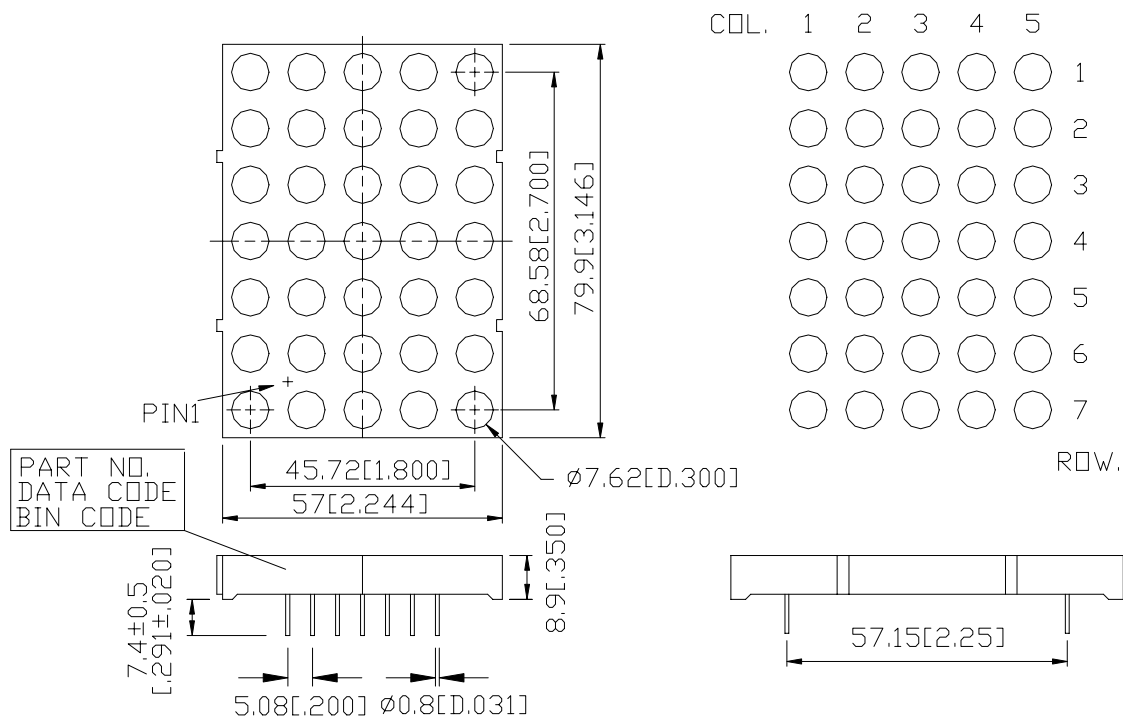
## **DESCRIPTION**

The is a 3.0 -inch ( 76.2 -mm) matrix height 5 × 7 dot-matrix display. This device utilizes ultra AlGaAs red LED chips, which are made from AlGaAs on a non-transparent GaAs substrate, and has a gray face and white dots.

## **DEVICE**

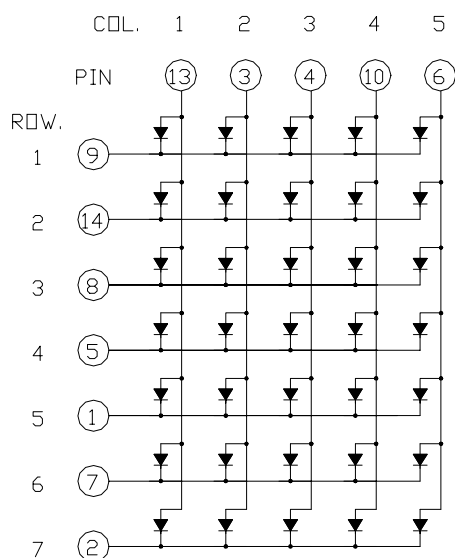
<b>PART NO.</b>	<b>DESCRIPTION</b>
AlGaAs RED	ANODE COLUMN
LTP-3057AC	CATHODE ROW

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$ -mm (0.01“) unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	CATHODE ROW 5
2	CATHODE ROW 7
3	ANODE COLUMN 2
4	ANODE COLUMN 3
5	CATHODE ROW 4
6	ANODE COLUMN 5
7	CATHODE ROW 6
8	CATHODE ROW 3
9	CATHODE ROW 1
10	ANODE COLUMN 4
11	NO CONNECTION
12	NO CONNECTION
13	ANODE COLUMN 1
14	CATHODE ROW 2

**ABSOLUTE MAXIMUM RATING AT T<sub>A</sub>=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	64	mW
Peak Forward Current Per Dot	110	mA
Continuous Forward Current Per Dot	14	mA
Derating Linear From 25°C Per Dot	0.19	mA/°C
Reverse Voltage Per Dot	10	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260°C		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT T<sub>A</sub>=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	11500	20000		μcd	I <sub>p</sub> =80mA, 1/16 Duty
Peak Emission Wavelength	λ <sub>p</sub>		660		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		35		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		638		nm	I <sub>F</sub> =20mA
Forward Voltage Per Dot	V <sub>F</sub>		3.6	4.8	V	I <sub>F</sub> =20mA
			4	5.4	V	I <sub>F</sub> =80mA
Reverse Current Per Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =10V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (commission internationale DE L'clairiage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

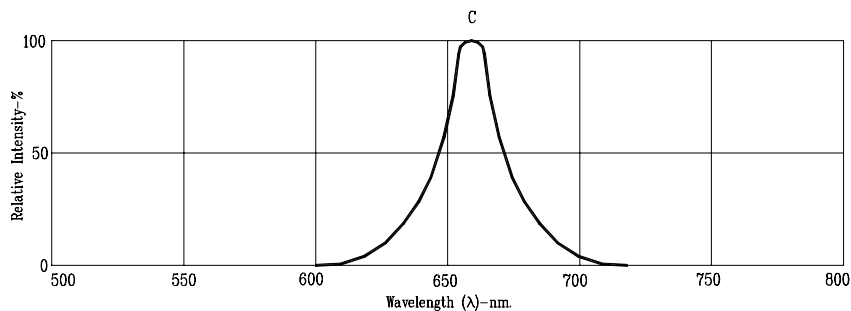


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

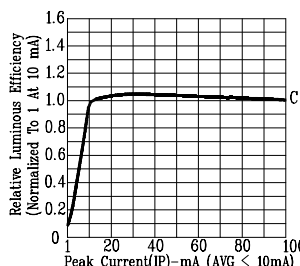


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

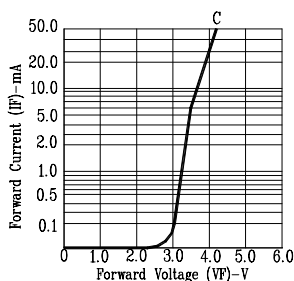


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

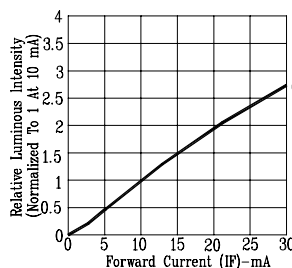


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

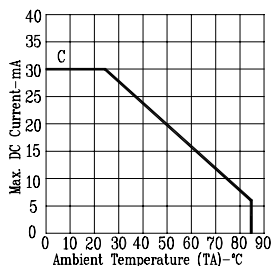


Fig5. MAX ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

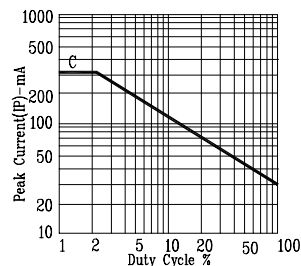


Fig6. MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: C=AlGaAs RED